

## SAM™ Data Sheet SAM-1040-3.5-6ps-x, λ = 1040 nm

Laser wavelength	λ = 1040 nm
High reflection band	λ = 990 1050 nm
Absorptance	A <sub>0</sub> = 3.5 %
Modulation depth	ΔR = 2.1 %
Non-saturable loss	A <sub>ns</sub> = 1.4 %
Saturation fluence	$\Phi_{sat}$ = 150 µJ/cm <sup>2</sup>
Relaxation time constant	τ = 6 ps
Damage threshold	$\Phi = 3 \text{ mJ/cm}^2$
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer
Mounting option x denotes the type of mounting as follows: x = 0 unmounted $x = 12.7 \text{ g}$ glued on a gold plated Cu-cylinder with 12.7 mm $\oslash$	

<b>x</b> = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm $arnothing$
<b>x</b> = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm $arnothing$
<b>x</b> = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm $arnothing$
<b>x</b> = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm $arnothing$
<b>x</b> = FC	mounted on a 1 m monomode fiber cable with FC connector

## Low intensity spectral reflectance

